

## 0.4-GHz TO 4-GHz QUADRATURE MODULATOR

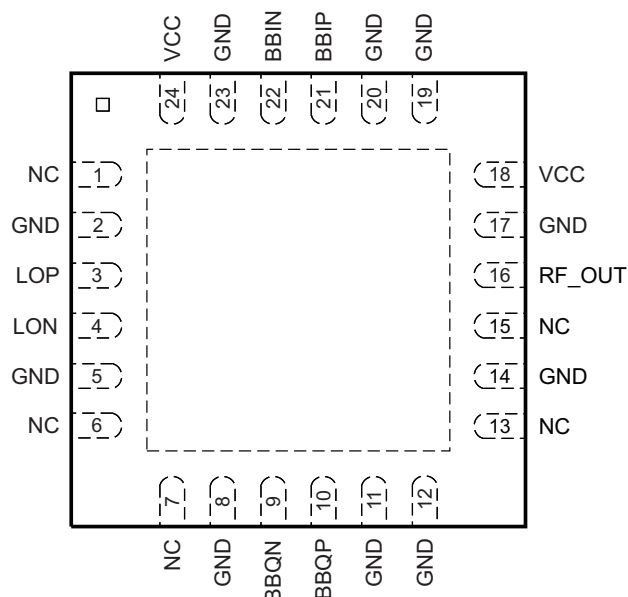
### FEATURES

- 75-dBc Single-Carrier WCDMA ACPR at –11-dBm Channel Power
- Very Low Noise Floor: –163 dBm/Hz
- OPI3 of 23 dBm
- P1dB of 9 dBm
- Unadjusted Carrier Feedthrough of –40 dBm
- Unadjusted Side-Band Suppression of –40 dBc
- Single Supply: 4.5 V–5.5 V Operation
- Silicon Germanium Technology
- TRF370333 With 3.3-V CM at I, Q Baseband Inputs
- TRF370315 With 1.5-V CM at I, Q Baseband Inputs

### APPLICATIONS

- Cellular Base Transceiver Station Transmit Channel
- CDMA: IS95, UMTS, CDMA2000, TD-SCDMA
- TDMA: GSM, IS-136, EDGE/UWC-136
- Wireless Local Loop
- Wireless MAN Wideband Transceivers

RGE PACKAGE  
(TOP VIEW)



P0024-04

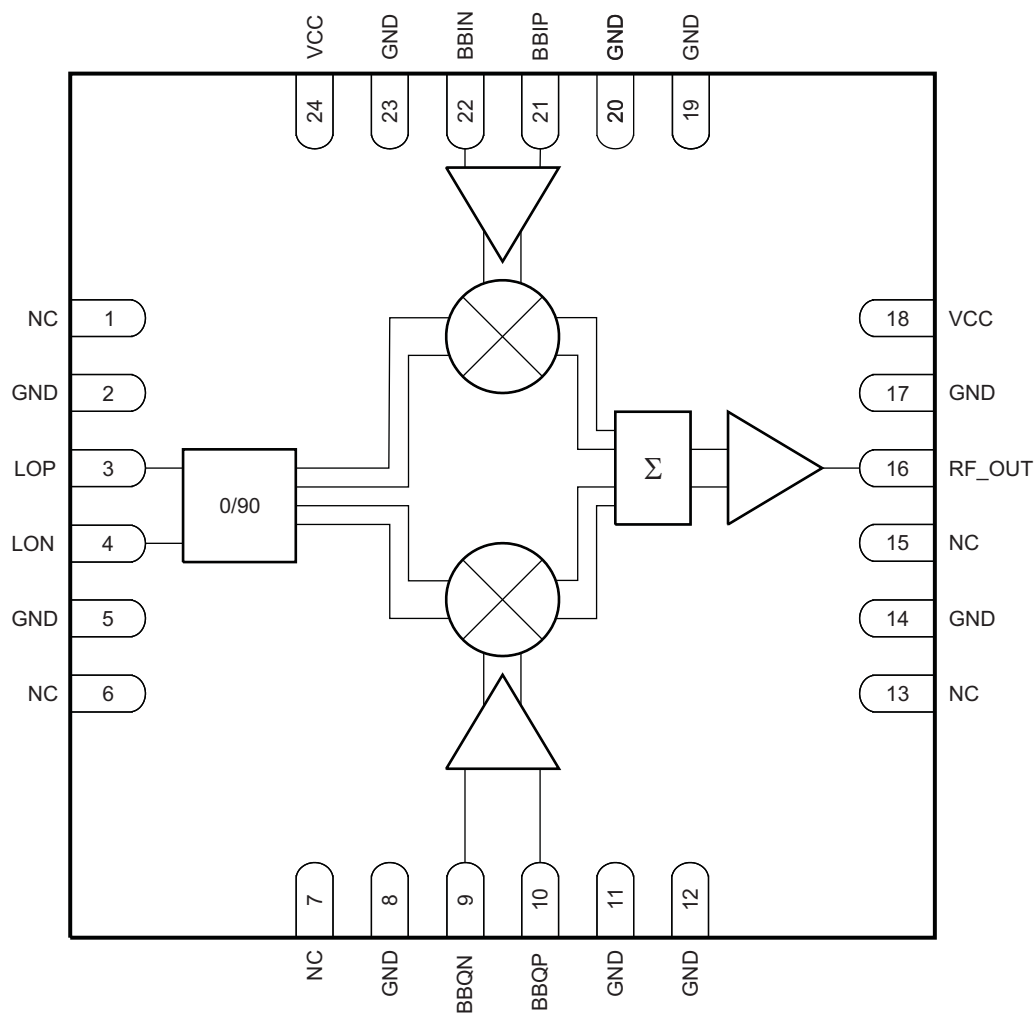
### DESCRIPTION

The TRF3703 is a very low-noise direct quadrature modulator, capable of converting complex modulated signals from baseband or IF directly up to RF. The TRF3703 is ideal for high-performance direct RF modulation from 400 MHz up to 4 GHz. The modulator is implemented as a double-balanced mixer. The RF output block consists of a differential to single-ended converter and an RF amplifier capable of driving a single-ended 50-Ω load without any need of external components. The TRF3703 comes in two types, TRF370333 and TRF370315. The TRF370333 and TRF370315 devices have different common-mode voltage ratings at the I, Q baseband inputs. The TRF370333 requires a 3.3-V common-mode voltage, and the TRF370315 requires a 1.5-V common-mode voltage.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Functional Block Diagram



B0175-01

NOTE: NC = No connection



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## DEVICE INFORMATION

### TERMINAL FUNCTIONS

| TERMINAL |                                     | I/O | DESCRIPTION            |
|----------|-------------------------------------|-----|------------------------|
| NAME     | NO.                                 |     |                        |
| BBIN     | 22                                  | I   | In-phase input         |
| BBIP     | 21                                  | I   | In-phase input         |
| BBQN     | 9                                   | I   | In-quadrature input    |
| BBQP     | 10                                  | I   | In-quadrature input    |
| GND      | 2, 5, 8, 11, 12, 14, 17, 19, 20, 23 | –   | Ground                 |
| LON      | 4                                   | I   | Local oscillator input |
| LOP      | 3                                   | I   | Local oscillator input |
| NC       | 1, 6, 7, 13, 15                     | –   | No connect             |
| RF_OUT   | 16                                  | O   | RF output              |
| VCC      | 18, 24                              | –   | Power supply           |

### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

|                                                    | VALUE <sup>(2)</sup>  | UNIT |
|----------------------------------------------------|-----------------------|------|
| Supply voltage range                               | –0.3 V to 6           | V    |
| Digital I/O voltage range                          | –0.3 V to $V_I + 0.3$ | V    |
| $T_J$ Operating virtual junction temperature range | –40 to 150            | °C   |
| $T_A$ Operating ambient temperature range          | –40 to 85             | °C   |
| $T_{stg}$ Storage temperature range                | –65 to 150            | °C   |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

### RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

|                               | MIN | NOM | MAX | UNIT |
|-------------------------------|-----|-----|-----|------|
| $V_{CC}$ Power-supply voltage | 4.5 | 5   | 5.5 | V    |

### THERMAL CHARACTERISTICS

| PARAMETER                                               | TEST CONDITIONS         | VALUE | UNIT |
|---------------------------------------------------------|-------------------------|-------|------|
| $R_{\theta JA}$ Thermal resistance, junction-to-ambient | High-K board, still air | 64.33 | °C/W |
| $R_{\theta JC}$ Thermal resistance, junction-to-case    |                         | 49.3  | °C/W |

**ELECTRICAL CHARACTERISTICS**

over operating free-air temperature range (unless otherwise noted)

| PARAMETER                     |                                       | TEST CONDITIONS       | MIN | TYP | MAX | UNIT |
|-------------------------------|---------------------------------------|-----------------------|-----|-----|-----|------|
| DC Parameters                 |                                       |                       |     |     |     |      |
| I <sub>CC</sub>               | Total supply current (1.5 V CM)       | T <sub>A</sub> = 25°C |     | 195 | 205 | mA   |
|                               | Total supply current (3.3 V CM)       | T <sub>A</sub> = 25°C |     | 210 | 235 |      |
| LO Input (50-Ω, Single-Ended) |                                       |                       |     |     |     |      |
| f <sub>LO</sub>               | LO frequency range                    |                       | 0.4 |     | 4   | GHz  |
|                               | LO input power                        |                       | −5  | 0   | 12  | dBm  |
|                               | LO port return loss                   |                       |     | 15  |     | dB   |
| Baseband Inputs               |                                       |                       |     |     |     |      |
| V <sub>CM</sub>               | I and Q input dc common voltage       | TRF370333             |     | 3.3 |     | V    |
|                               |                                       | TRF370315             |     | 1.5 |     |      |
| BW                            | 1-dB input frequency bandwidth        |                       | 350 |     |     | MHz  |
| Z <sub>I(single ended)</sub>  | Input impedance, resistance           | TRF370333             |     | 10  |     | kΩ   |
|                               | Input impedance, parallel capacitance |                       |     | 3   |     | pF   |
|                               | Input impedance, resistance           | TRF370315             |     | 5   |     | kΩ   |
|                               | Input impedance, parallel capacitance |                       |     | 3   |     | pF   |

**ELECTRICAL CHARACTERISTICS**over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 400\text{ MHz}$  at 0 dBm (unless otherwise noted)

| <b>RF Output Parameters</b> |                          |                                                    |     |      |     |      |
|-----------------------------|--------------------------|----------------------------------------------------|-----|------|-----|------|
| PARAMETER                   |                          | TEST CONDITIONS                                    | MIN | TYP  | MAX | UNIT |
| G                           | Voltage gain             | Output rms voltage over input I (or Q) rms voltage |     | –2.3 |     | dB   |
| P1dB                        | Output compression point |                                                    |     | 9.4  |     | dBm  |
| IP3                         | Output IP3               |                                                    | 20  | 23   |     | dBm  |
| IP2                         | Output IP2               | Measured at $f_{LO} + 2 \times f_{BB}$             |     | 62   |     | dBm  |
|                             | Carrier feedthrough      | Unadjusted                                         |     | –37  |     | dBm  |
|                             | Sideband suppression     | Unadjusted                                         |     | –39  |     | dBc  |

## ELECTRICAL CHARACTERISTICS

over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 900\text{ MHz}$  at 0 dBm (unless otherwise noted)

| RF Output Parameters |                                                                    |                                                                                                                     |     |        |        |
|----------------------|--------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------|-----|--------|--------|
| PARAMETER            | TEST CONDITIONS                                                    | MIN                                                                                                                 | TYP | MAX    | UNIT   |
| G                    | Voltage gain                                                       | Output rms voltage over input I (or Q) rms voltage                                                                  |     | –4.1   | dB     |
| P1dB                 | Output compression point                                           |                                                                                                                     |     | 9      | dBm    |
| IP3                  | Output IP3                                                         | 20                                                                                                                  | 23  |        | dBm    |
| IP2                  | Output IP2                                                         | Measured at $f_{LO} + 2 \times f_{BB}$                                                                              |     | 63     | dBm    |
|                      | Carrier feedthrough                                                | Unadjusted                                                                                                          |     | –37    | dBm    |
|                      | Sideband suppression                                               | Unadjusted                                                                                                          |     | –42    | dBc    |
|                      | Output return loss                                                 |                                                                                                                     |     | 9      | dB     |
| Output noise floor   | DC only to BB inputs, 13 MHz offset from $f_{LO}$                  |                                                                                                                     |     | –160.4 | dBm/Hz |
|                      | 1.8-MHz offset from $f_{LO}$ ; 1 CW tone; $P_{out} = 0\text{ dBm}$ |                                                                                                                     |     | –156.6 |        |
|                      | 6-MHz offset from $f_{LO}$ ; 1 CW tone; $P_{out} = 0\text{ dBm}$   |                                                                                                                     |     | –158.5 |        |
| EVM                  | Error vector magnitude (rms)                                       | 1 EDGE signal, $P_{out} = -5\text{ dBm}$                                                                            |     | 0.59%  |        |
|                      |                                                                    | 1 EDGE signal, $P_{out} = 0\text{ dBm}$                                                                             |     | 0.63%  |        |
|                      |                                                                    | 1 EDGE signal, $P_{out} = 0\text{ dBm}$ , 2nd harmonic of LO = –15 dBm, 3rd harmonic of LO = –33 dBm <sup>(1)</sup> |     | 1%     |        |

(1) The second- and third-harmonic tests were made independently at each frequency.

## ELECTRICAL CHARACTERISTICS

over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 1800\text{ MHz}$  at 0 dBm (unless otherwise noted)

| RF Output Parameters |                                                                    |                                                                                                                       |     |        |        |
|----------------------|--------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------|-----|--------|--------|
| PARAMETER            | TEST CONDITIONS                                                    | MIN                                                                                                                   | TYP | MAX    | UNIT   |
| G                    | Voltage gain                                                       | Output rms voltage over input I (or Q) rms voltage                                                                    |     | –4.4   | dB     |
| P1dB                 | Output compression point                                           |                                                                                                                       |     | 9.5    | dBm    |
| IP3                  | Output IP3                                                         | 20                                                                                                                    | 23  |        | dBm    |
| IP2                  | Output IP2                                                         | Measured at $f_{LO} + 2 \times f_{BB}$                                                                                |     | 55     | dBm    |
|                      | Carrier feedthrough                                                | Unadjusted                                                                                                            |     | –40    | dBm    |
|                      | Sideband suppression                                               | Unadjusted                                                                                                            |     | –47    | dBc    |
|                      | Output return loss                                                 |                                                                                                                       |     | 8      | dB     |
| Output noise floor   | DC only to BB inputs, 13 MHz offset from $f_{LO}$                  |                                                                                                                       |     | –162.6 | dBm/Hz |
|                      | 1.8-MHz offset from $f_{LO}$ ; 1 CW tone; $P_{out} = 0\text{ dBm}$ |                                                                                                                       |     | –160   |        |
|                      | 6-MHz offset from $f_{LO}$ ; 1 CW tone; $P_{out} = 0\text{ dBm}$   |                                                                                                                       |     | –159.4 |        |
| EVM                  | Error vector magnitude (rms)                                       | 1 EDGE signal, $P_{out} = -5\text{ dBm}$                                                                              |     | 0.66%  |        |
|                      |                                                                    | 1 EDGE signal, $P_{out} = 0\text{ dBm}$                                                                               |     | 0.74%  |        |
|                      |                                                                    | 1 EDGE signal, $P_{out} = 0\text{ dBm}$ , 2nd harmonic of LO = –15.5 dBm, 3rd harmonic of LO = –30 dBm <sup>(1)</sup> |     | 1%     |        |

(1) The second- and third-harmonic tests were made independently at each frequency.

**ELECTRICAL CHARACTERISTICS**

over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 2140\text{ MHz}$  at 0 dBm (unless otherwise noted)

| RF Output Parameters              |                                                                                              |     |       |     |        |
|-----------------------------------|----------------------------------------------------------------------------------------------|-----|-------|-----|--------|
| PARAMETER                         | TEST CONDITIONS                                                                              | MIN | TYP   | MAX | UNIT   |
| G Voltage gain                    | Output rms voltage over input I (or Q) rms voltage                                           |     | –4.5  |     | dB     |
| P1dB Output compression point     |                                                                                              |     | 9.5   |     | dBm    |
| IP3 Output IP3                    |                                                                                              | 18  | 21    |     | dBm    |
| IP2 Output IP2                    | Measured at $f_{LO} + 2 \times f_{BB}$                                                       |     | 58    |     | dBm    |
| Carrier feedthrough               | Unadjusted                                                                                   |     | –40   |     | dBm    |
| Sideband suppression              | Unadjusted                                                                                   |     | –47   |     | dBc    |
| Output return loss                |                                                                                              |     | 8.5   |     | dB     |
| Output noise floor                | 20-MHz offset from $f_{LO}$ ; dc only to BB inputs                                           |     | –163  |     | dBm/Hz |
|                                   | 20-MHz offset from $f_{LO}$ ; 1 WCDMA signal; $P_{in} = -20.5\text{ dBVrms}$ (I and Q input) |     | –162  |     |        |
| ACPR Adjacent-channel power ratio | 1 WCDMA signal; $P_{out} = -13\text{ dBm}$                                                   |     | –75.8 |     | dBc    |
|                                   | 1 WCDMA signal; $P_{out} = -9\text{ dBm}$                                                    |     | –72   |     |        |
|                                   | 4 WCDMA signals; $P_{out} = -23\text{ dBm}$ per carrier                                      |     | –68   |     |        |
| Alternate-channel power ratio     | 1 WCDMA signal; $P_{out} = -13\text{ dBm}$                                                   |     | –79   |     | dBc    |
|                                   | 1 WCDMA signal; $P_{out} = -9\text{ dBm}$                                                    |     | –80.5 |     |        |
|                                   | 4 WCDMA signals; $P_{out} = -23\text{ dBm}$ per carrier                                      |     | –69   |     |        |

**ELECTRICAL CHARACTERISTICS**

over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 2500\text{ MHz}$  at 0 dBm (unless otherwise noted)

| RF Output Parameters          |                                                    |     |      |     |      |
|-------------------------------|----------------------------------------------------|-----|------|-----|------|
| PARAMETER                     | TEST CONDITIONS                                    | MIN | TYP  | MAX | UNIT |
| G Voltage gain                | Output rms voltage over input I (or Q) rms voltage |     | –4.4 |     | dB   |
| P1dB Output compression point |                                                    |     | 9.5  |     | dBm  |
| IP3 Output IP3                |                                                    | 18  | 21   |     | dBm  |
| IP2 Output IP2                | Measured at $f_{LO} + 2 \times f_{BB}$             |     | 63   |     | dBm  |
| Carrier feedthrough           | Unadjusted                                         |     | –38  |     | dBm  |
| Sideband suppression          | Unadjusted                                         |     | –47  |     | dBc  |

**ELECTRICAL CHARACTERISTICS**

over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 3600\text{ MHz}$  at 0 dBm (unless otherwise noted)

| RF Output Parameters          |                                                    |     |      |     |      |
|-------------------------------|----------------------------------------------------|-----|------|-----|------|
| PARAMETER                     | TEST CONDITIONS                                    | MIN | TYP  | MAX | UNIT |
| G Voltage gain                | Output rms voltage over input I (or Q) rms voltage |     | –3.5 |     | dB   |
| P1dB Output compression point |                                                    |     | 9.5  |     | dBm  |
| IP3 Output IP3                |                                                    | 20  | 23   |     | dBm  |
| IP2 Output IP2                | Measured at $f_{LO} + 2 \times f_{BB}$             |     | 63   |     | dBm  |
| Carrier feedthrough           | Unadjusted                                         |     | –41  |     | dBm  |
| Sideband suppression          | Unadjusted                                         |     | –45  |     | dBc  |

## ELECTRICAL CHARACTERISTICS

over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 4000 \text{ MHz}$  at 0 dBm (unless otherwise noted)

| RF Output Parameters |                          |                                                    |     |      |      |
|----------------------|--------------------------|----------------------------------------------------|-----|------|------|
| PARAMETER            | TEST CONDITIONS          | MIN                                                | TYP | MAX  | UNIT |
| G                    | Voltage gain             | Output rms voltage over input I (or Q) rms voltage |     | –4.5 | dB   |
| P1dB                 | Output compression point |                                                    |     | 9    | dBm  |
| IP3                  | Output IP3               |                                                    |     | 19   | dBm  |
| IP2                  | Output IP2               | Measured at $f_{LO} + 2 \times f_{BB}$             |     | 50   | dBm  |
|                      | Carrier feedthrough      | Unadjusted                                         |     | –37  | dBm  |
|                      | Sideband suppression     | Unadjusted                                         |     | –40  | dBc  |

## TYPICAL CHARACTERISTICS

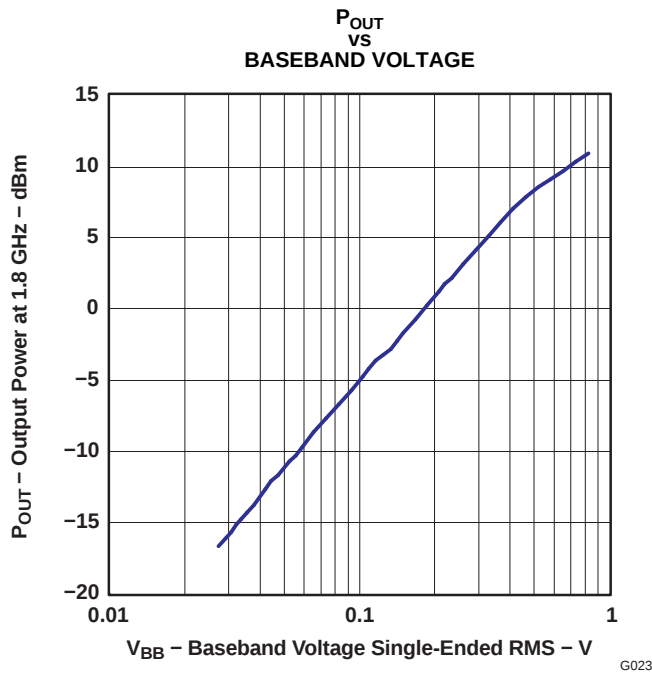


Figure 1.

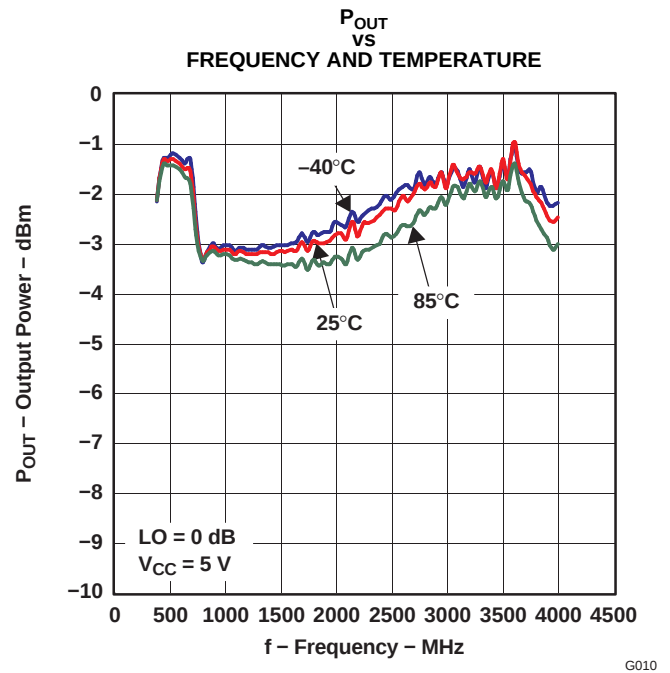


Figure 2.

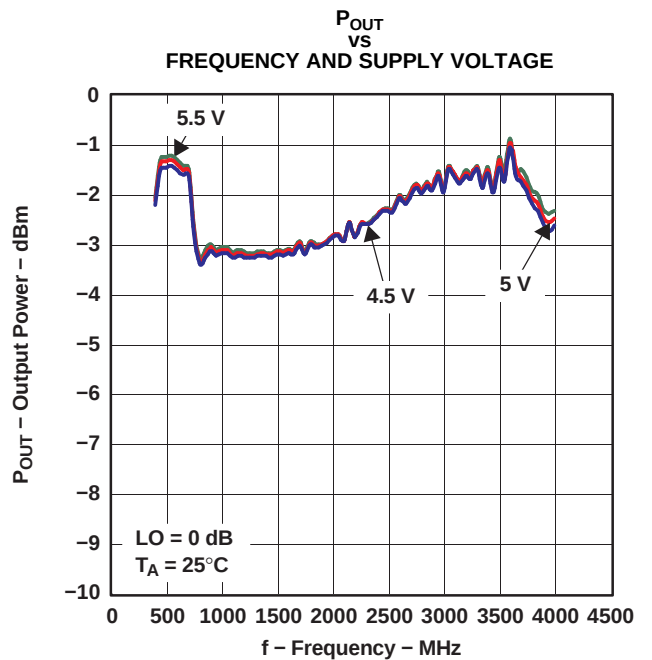


Figure 3.

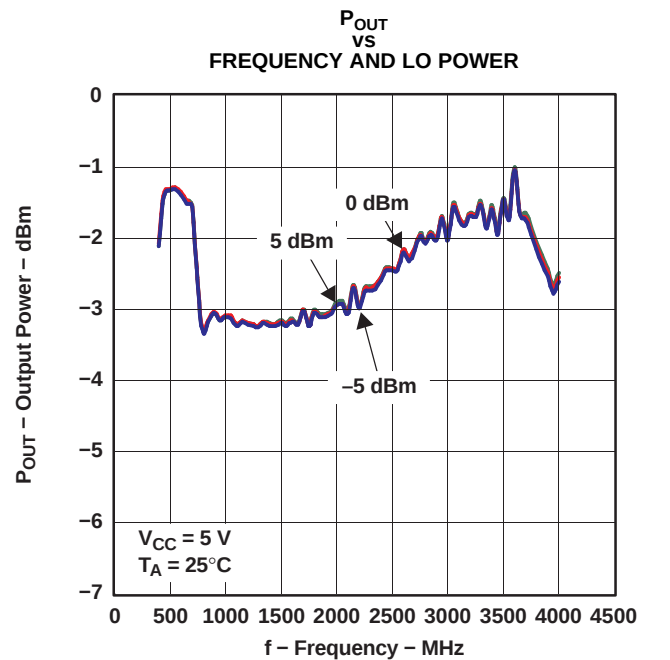
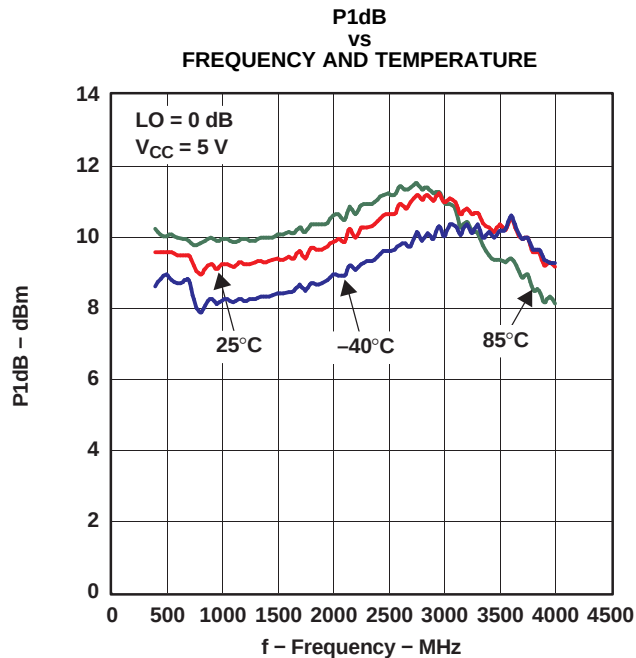


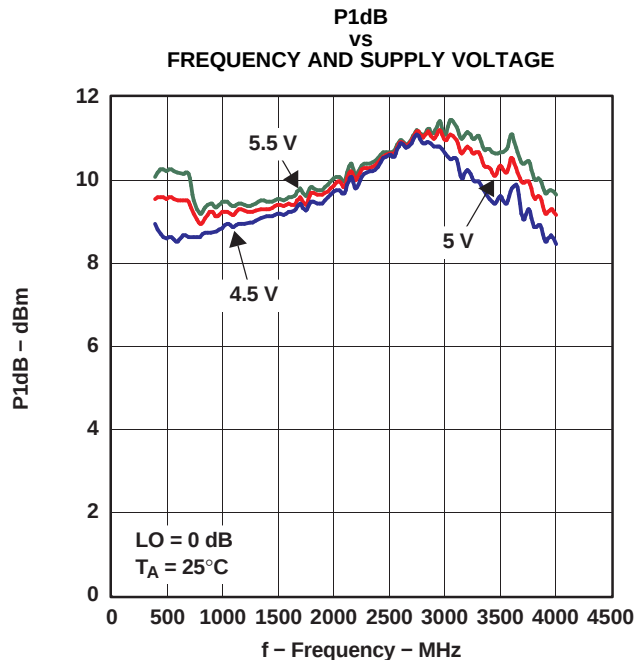
Figure 4.

## TYPICAL CHARACTERISTICS (continued)



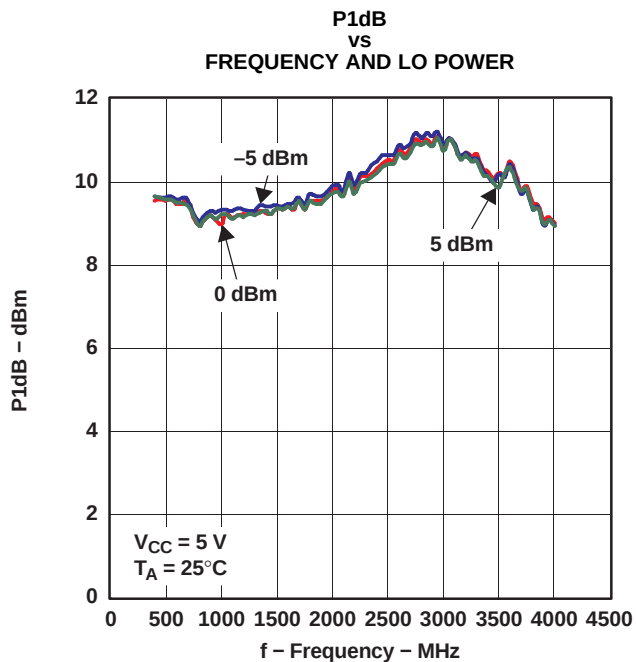
G001

Figure 5.



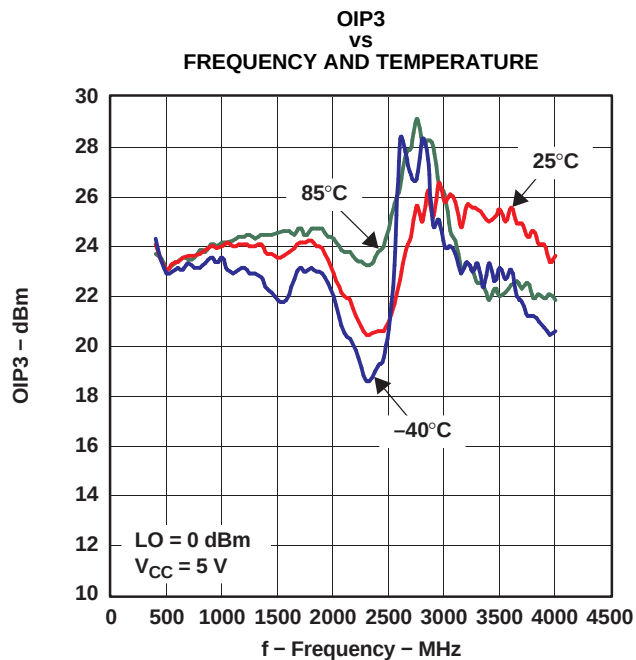
G002

Figure 6.



G003

Figure 7.



G014

Figure 8.

## TYPICAL CHARACTERISTICS (continued)

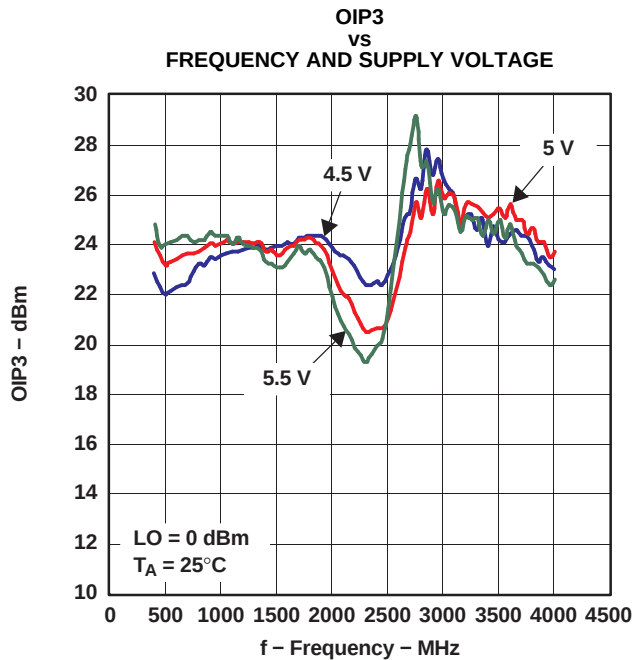


Figure 9.

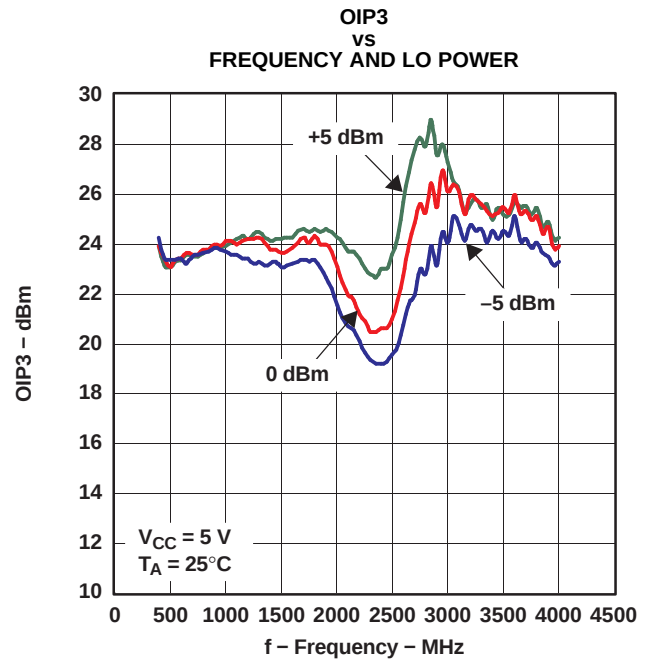


Figure 10.

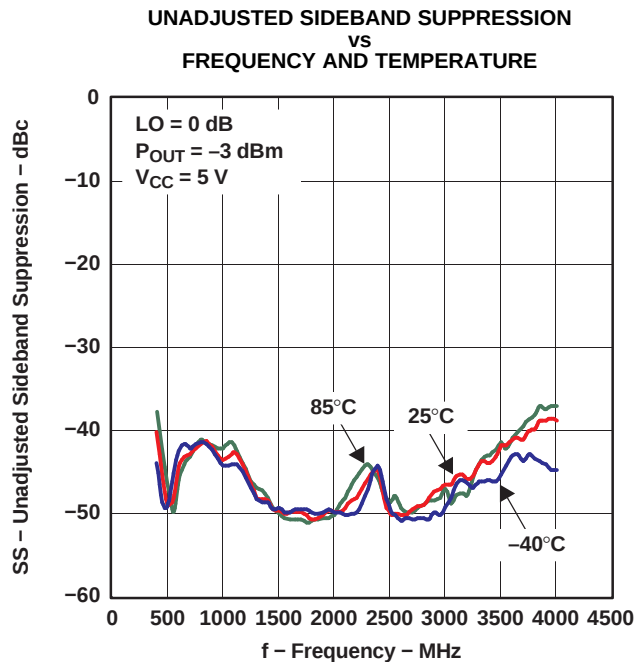


Figure 11.

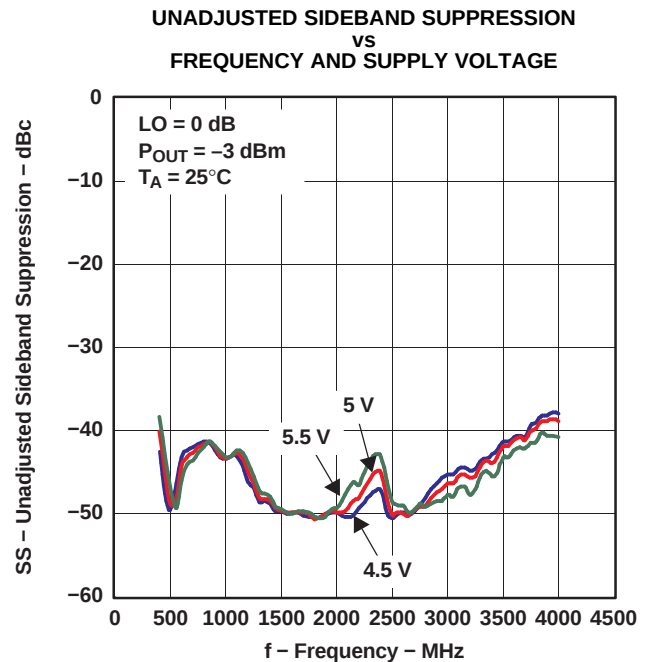


Figure 12.

## TYPICAL CHARACTERISTICS (continued)

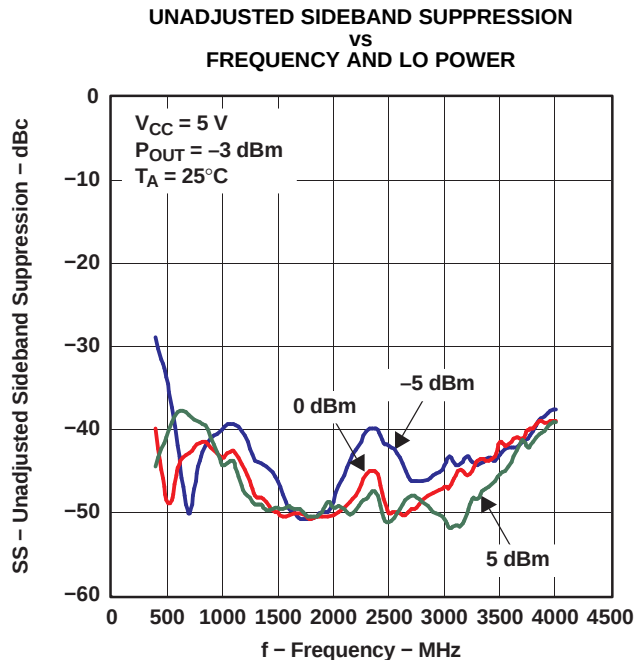


Figure 13.

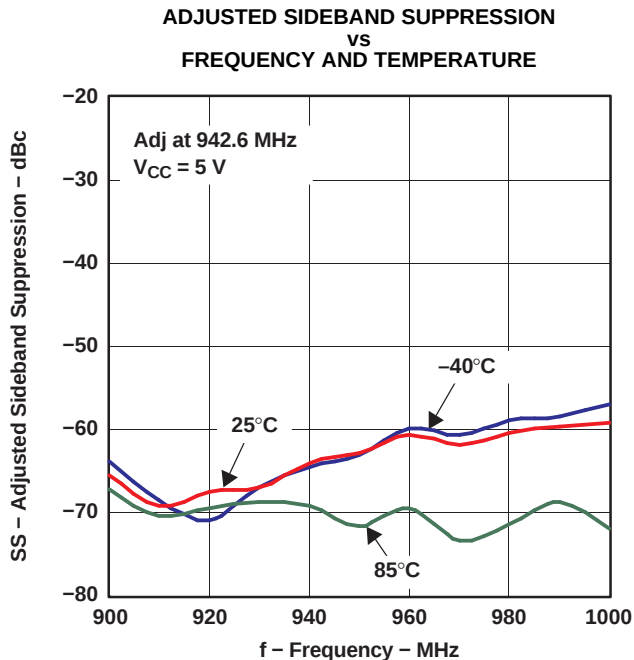


Figure 14.

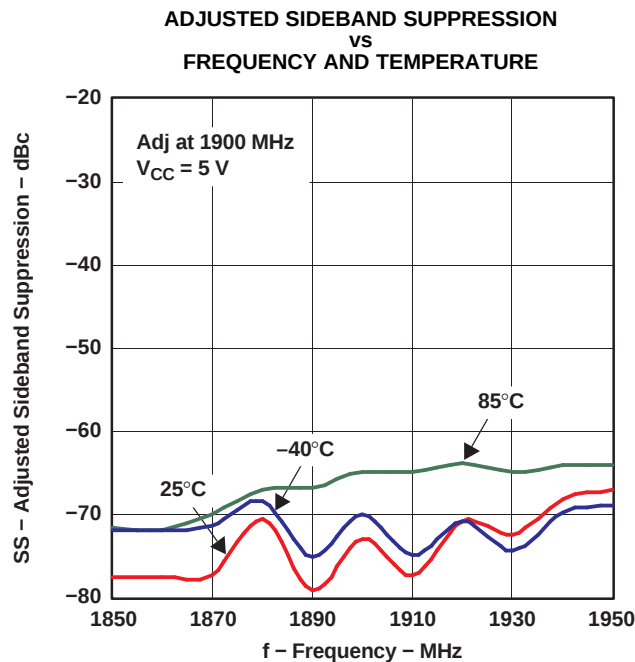


Figure 15.

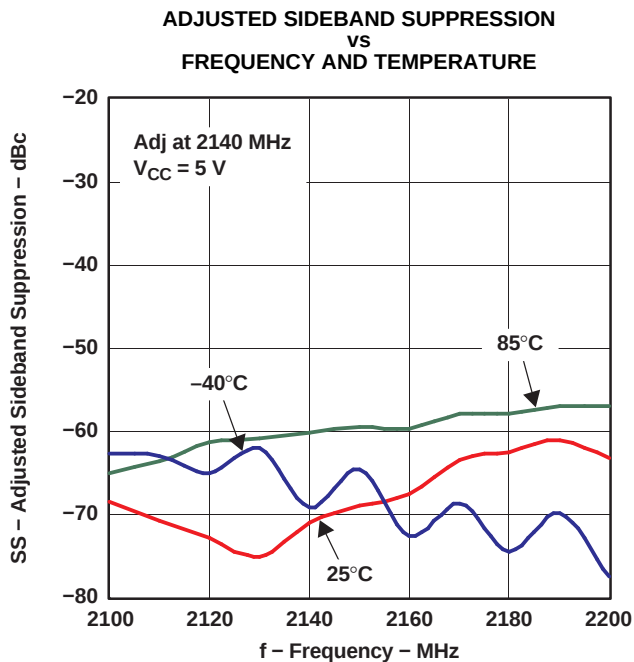


Figure 16.

## TYPICAL CHARACTERISTICS (continued)

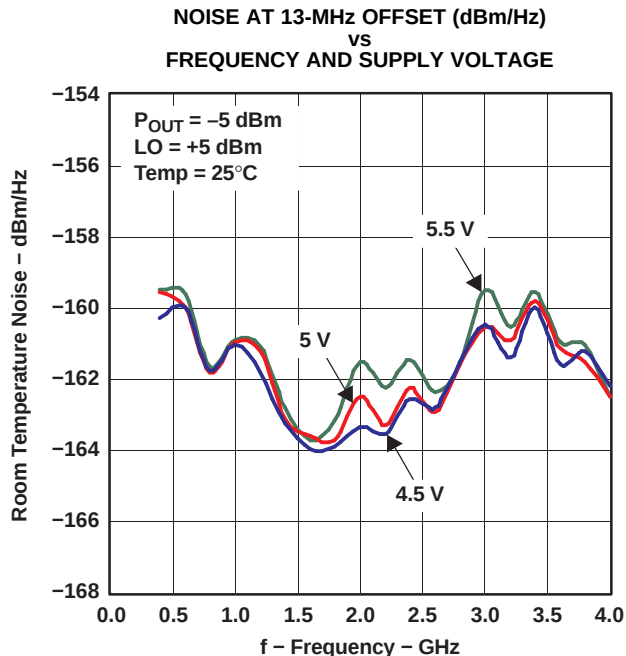


Figure 17.

G019

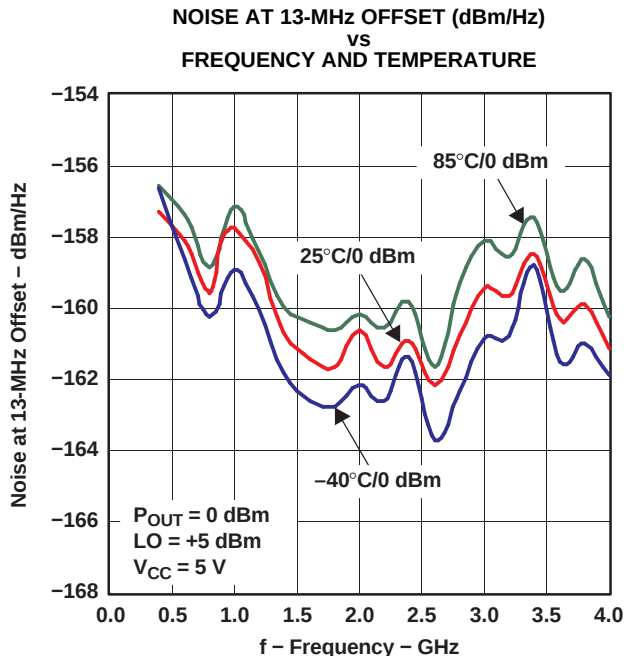


Figure 18.

G020

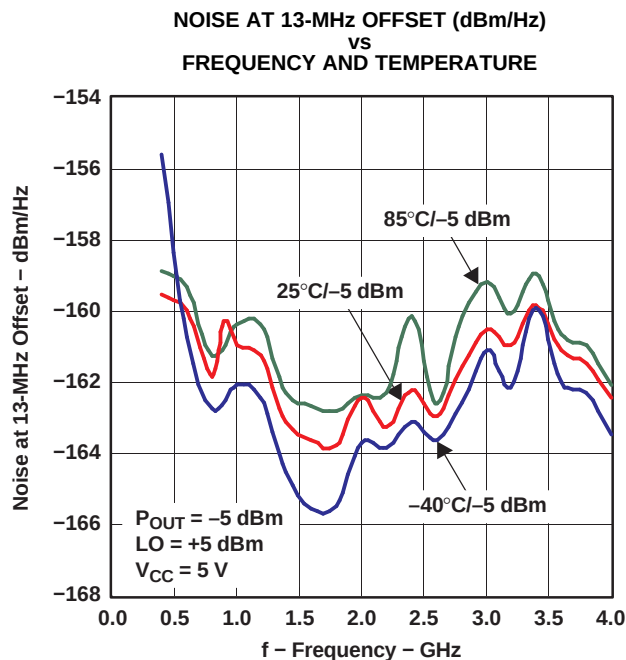


Figure 19.

G021

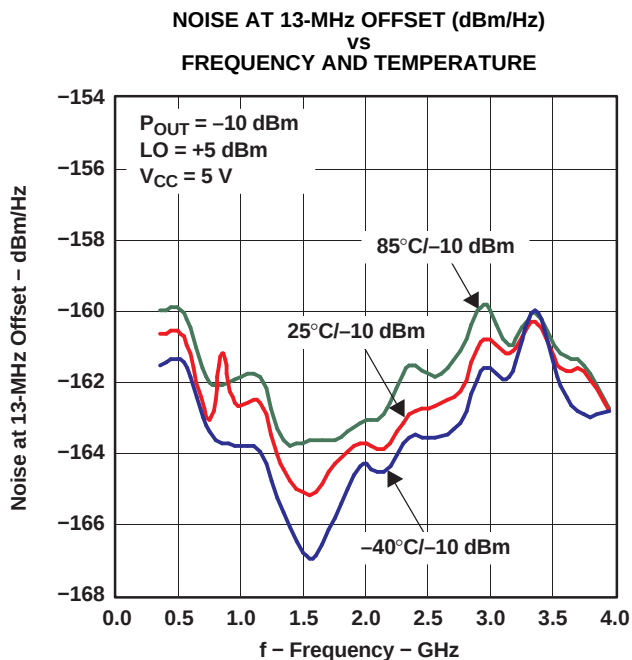


Figure 20.

G022

## TYPICAL CHARACTERISTICS (continued)

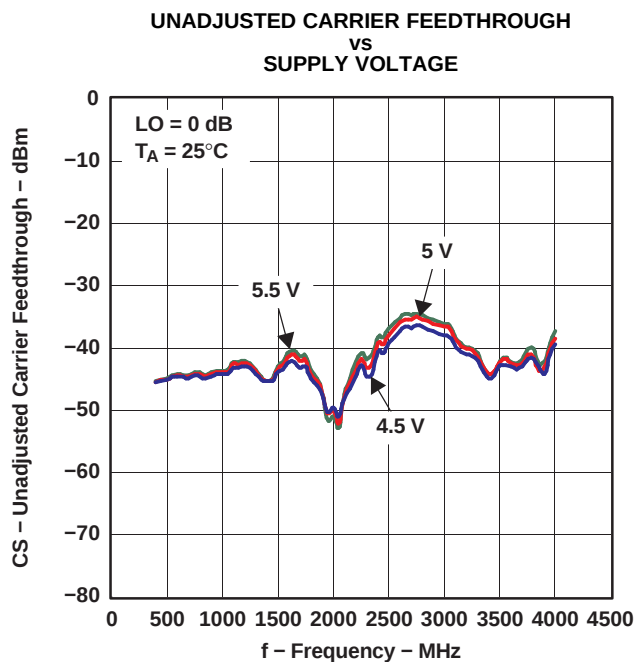


Figure 21.

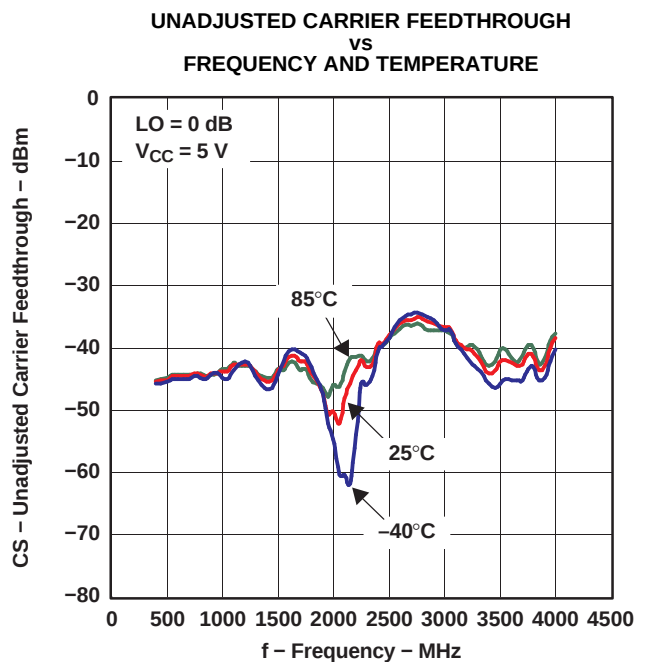
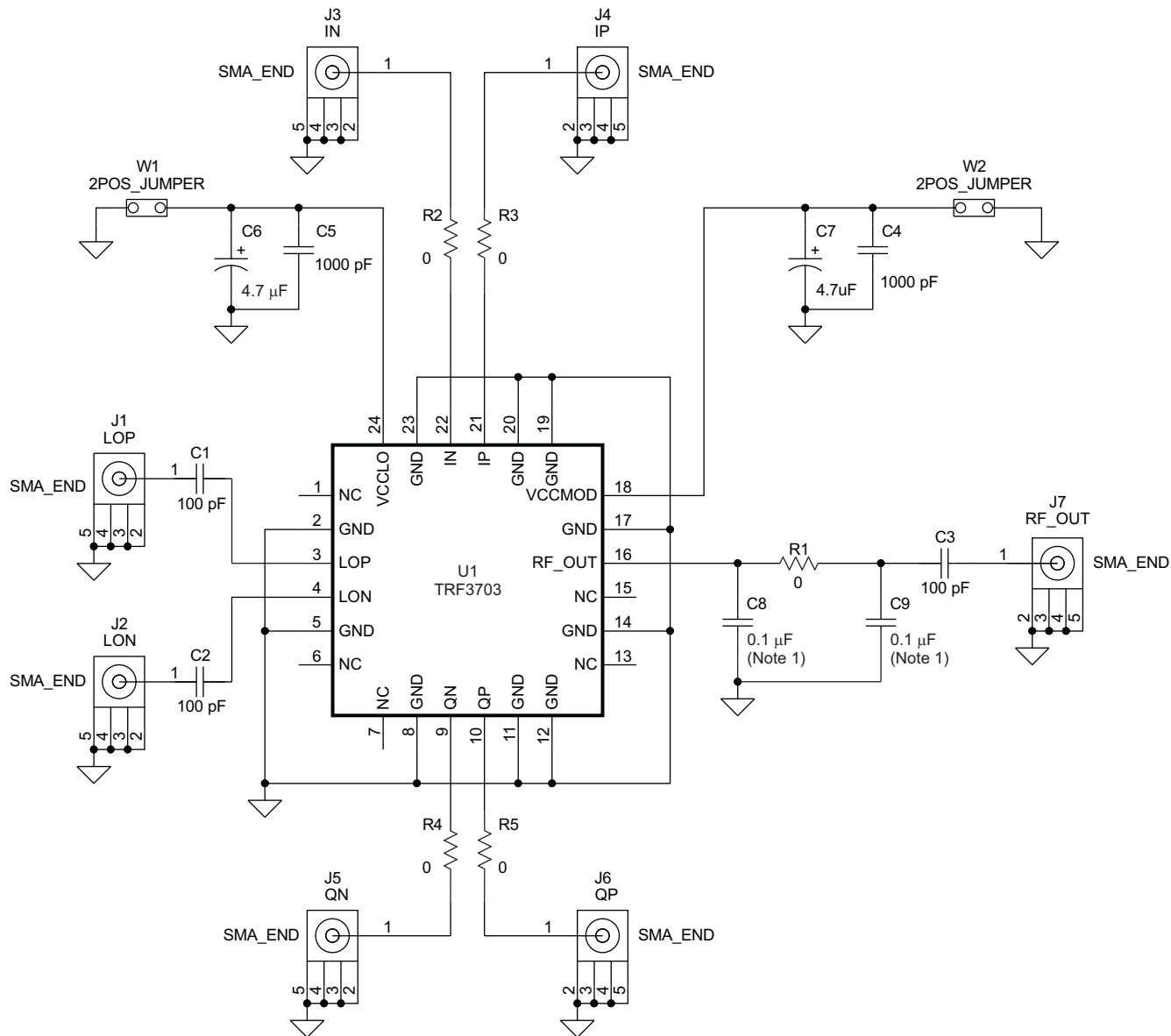


Figure 22.

**APPLICATION INFORMATION AND EVALUATION BOARD****Basic Connections**

- See [Figure 23](#) for proper connection of the TRF3703 modulator.
- Connect a single power supply (4.5 V–5.5 V) to pins 18 and 24. These pins should be decoupled as shown on pins 4, 5, 6, and 7.
- Connect pins 2, 5, 8, 11, 12, 14, 17, 19, 20, and 23 to GND.
- Connect a single-ended LO source of desired frequency to LOP (amplitude between –5 dBm and 12 dBm). This should be ac-coupled through a 100-pF capacitor.
- Terminate the ac-coupled LON with 50  $\Omega$  to GND.
- Connect a baseband signal to pins 21 = I, 22 =  $\bar{I}$ , 10 = Q, and 9 =  $\bar{Q}$ .
- The differential baseband inputs should be set to the proper level, 3.3 V for the TRF370333 or 1.5 V for the TRF370315.
- RF\_OUT, pin 16, can be fed to a spectrum analyzer set to the desired frequency, LO  $\pm$  baseband signal. This pin should also be ac-coupled through a 100-pF capacitor.
- All NC pins can be left floating.

# APPLICATION INFORMATION AND EVALUATION BOARD (continued)



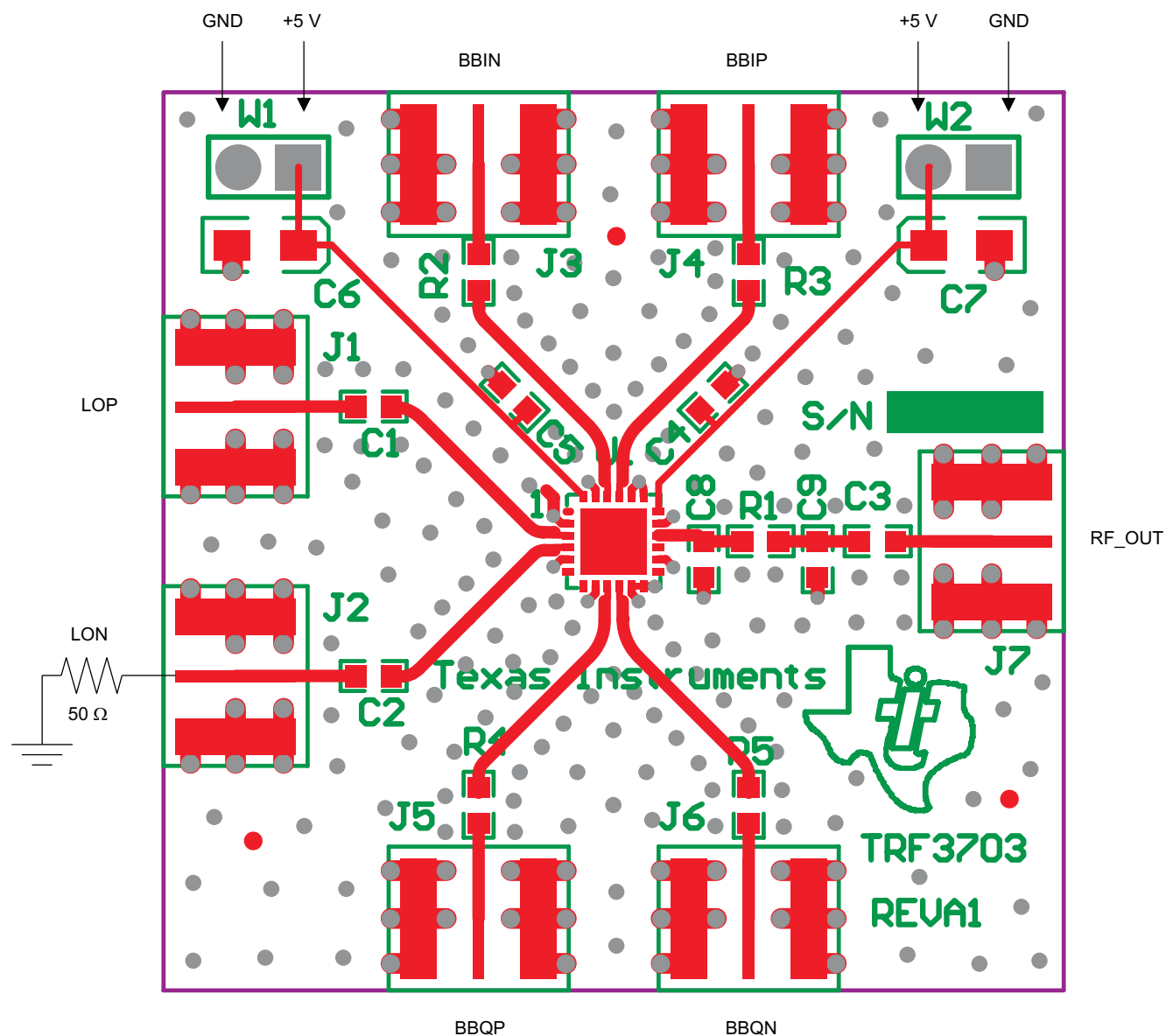
S0214-01

(1) Do not install.

Figure 23. TRF3703 EVM Schematic

**APPLICATION INFORMATION AND EVALUATION BOARD (continued)**

Figure 24 shows the top view of the TRF3703 EVM board.



K001

**Figure 24. TRF3703 EVM Board Layout**

**Table 1. Bill of Materials for TRF3703 EVM**

| Value                                            | Footprint | QTY | Part Number    | Vendor    | Digi-Key Number | REF DES    | Not Installed |
|--------------------------------------------------|-----------|-----|----------------|-----------|-----------------|------------|---------------|
| Tantalum<br>4.7- $\mu$ F, 10-V,<br>10% capacitor | 3216      | 2   | T491A475K010AS | KEMET     | 399-1561-1-ND   | C6, C7     |               |
| 1000-pF, 50-V,<br>5% capacitor                   | 603       | 2   | ECJ-1VC1H102J  | Panasonic | PCC2151CT-ND    | C4, C5     |               |
| 100-pF, 50-V,<br>5% capacitor                    | 603       | 3   | ECJ-1VC1H101J  | Panasonic | PCC101ACVCT-ND  | C1, C2, C3 |               |
| Capacitor                                        | 603       | 0   |                |           |                 |            | C8, C9        |

## APPLICATION INFORMATION AND EVALUATION BOARD (continued)

Table 1. Bill of Materials for TRF3703 EVM (continued)

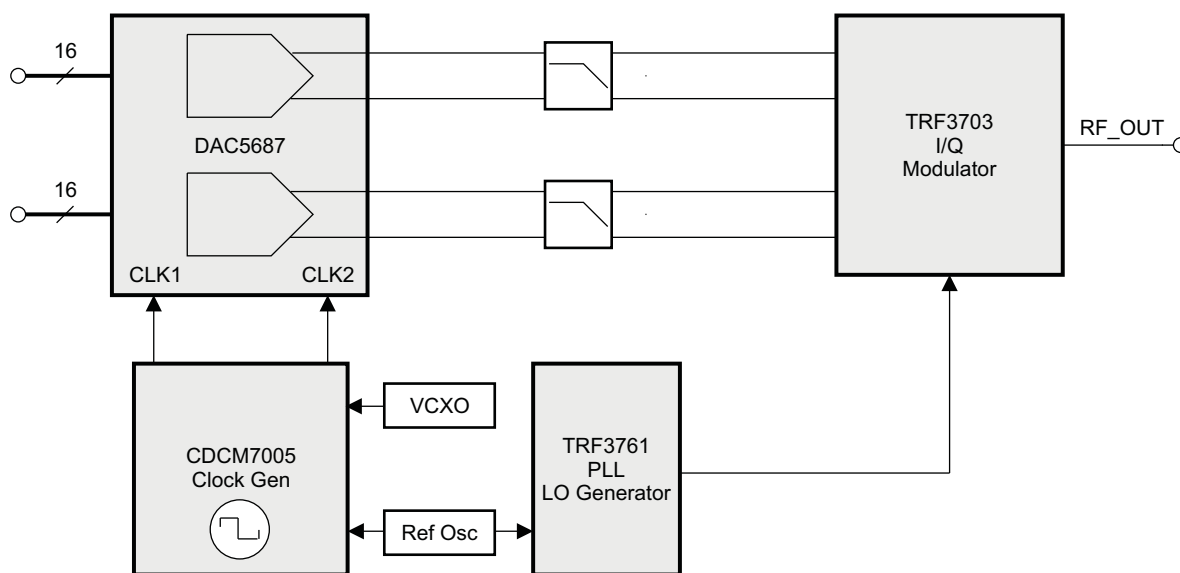
| Value                    | Footprint       | QTY | Part Number     | Vendor    | Digi-Key Number | REF DES                    | Not Installed |
|--------------------------|-----------------|-----|-----------------|-----------|-----------------|----------------------------|---------------|
| 0-Ω resistor, 1/10-W, 5% | 603             | 5   | ERJ-3GEY0R00V   | Panasonic | P0.0GCT-ND      | R1, R2, R3, R4, R5         |               |
| TRF3703                  | 24-QFN-PP-4X4MM | 1   |                 | TI        |                 | U1                         |               |
| SMA connectors           | SMA_END_SMALL   | 6   | 16F3627         | Newark    | 142-0711-821    | J1, J2, J3, J4, J5, J6, J7 |               |
| 2POS_HEADER              | 2POS_JUMP       | 2   | HTSW-150-07-L-S | SAMTEC    | N/A             | W1, W2                     |               |

### GSM Applications

The TRF3703 is suited for GSM applications because of its high linearity and low noise level over the entire recommended operating range. It also has excellent EVM performance, which makes it ideal for the stringent GSM/EDGE applications.

### WCDMA Applications

The TRF3703 is also optimized for WCDMA applications where both adjacent-channel power ratio (ACPR) and noise density are critically important. Using Texas instruments' DAC568X series of high-performance digital-to-analog converters as depicted in [Figure 25](#), excellent ACPR levels were measured with one-, two-, and four-WCDMA carriers. See *Electrical Characteristics*,  $f_{LO} = 2140$  MHz for exact ACPR values.



B0176-01

Figure 25. Typical Transmit Setup Block Diagram

## DEFINITION OF SPECIFICATIONS

### Unadjusted Carrier Feedthrough

This specification measures the amount by which the local oscillator component is attenuated in the output spectrum of the modulator relative to the carrier. This further assumes that the baseband inputs delivered to the pins of the TRF3703 are perfectly matched to have the same dc offset (VCM). This includes all four baseband inputs: I,  $\bar{I}$ , Q, and  $\bar{Q}$ . This is measured in dBm.

### Adjusted (Optimized) Carrier Feedthrough

This differs from the unadjusted suppression number in that the baseband input dc offsets are iteratively adjusted around their theoretical value of VCM to yield the maximum suppression of the LO component in the output spectrum. This is measured in dBm.

### Unadjusted Sideband Suppression

This specification measures the amount by which the unwanted sideband of the input signal is attenuated in the output of the modulator, relative to the wanted sideband. This further assumes that the baseband inputs delivered to the modulator input pins are perfectly matched in amplitude and are exactly 90° out of phase. This is measured in dBc.

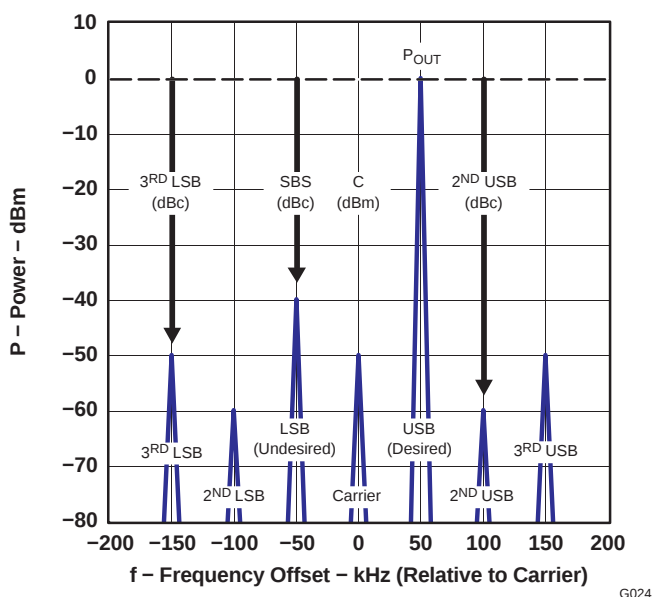
### Adjusted (Optimized) Sideband Suppression

This differs from the unadjusted sideband suppression in that the baseband inputs are iteratively adjusted around their theoretical values to maximize the amount of sideband suppression. This is measured in dBc.

### Suppressions Over Temperature

This specification assumes that the user has gone through the optimization process for the suppression in question, and set the optimal settings for the I, Q inputs. This specification then measures the suppression when temperature conditions change after the initial calibration is done.

Figure 26 shows a simulated output and illustrates the respective definitions of various terms used in this data sheet. The graph assumes a baseband input of 50 kHz.



G024

Figure 26. Graphical Illustration of Common Terms

## PACKAGING INFORMATION

| Orderable Device | Status <sup>(1)</sup> | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <sup>(2)</sup> | Lead/Ball Finish | MSL Peak Temp <sup>(3)</sup> |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|------------------|------------------------------|
| TRF370315IRGER   | ACTIVE                | QFN          | RGE             | 24   | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-3-260C-168 HR          |
| TRF370315IRGET   | ACTIVE                | QFN          | RGE             | 24   | 250         | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-3-260C-168 HR          |
| TRF370333IRGER   | ACTIVE                | QFN          | RGE             | 24   | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-3-260C-168 HR          |
| TRF370333IRGERG4 | ACTIVE                | QFN          | RGE             | 24   | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-3-260C-168 HR          |
| TRF370333IRGET   | ACTIVE                | QFN          | RGE             | 24   | 250         | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-3-260C-168 HR          |
| TRF370333IRGETG4 | ACTIVE                | QFN          | RGE             | 24   | 250         | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-3-260C-168 HR          |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

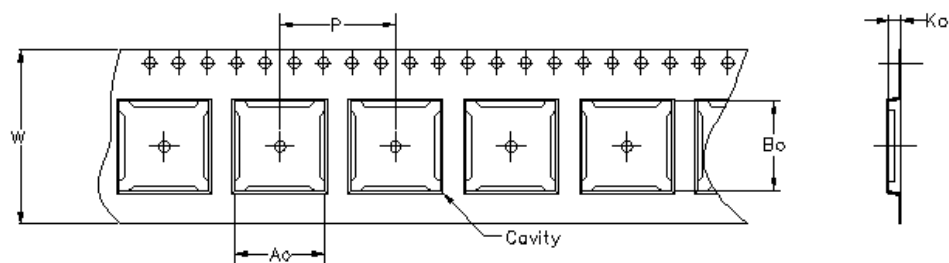
**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

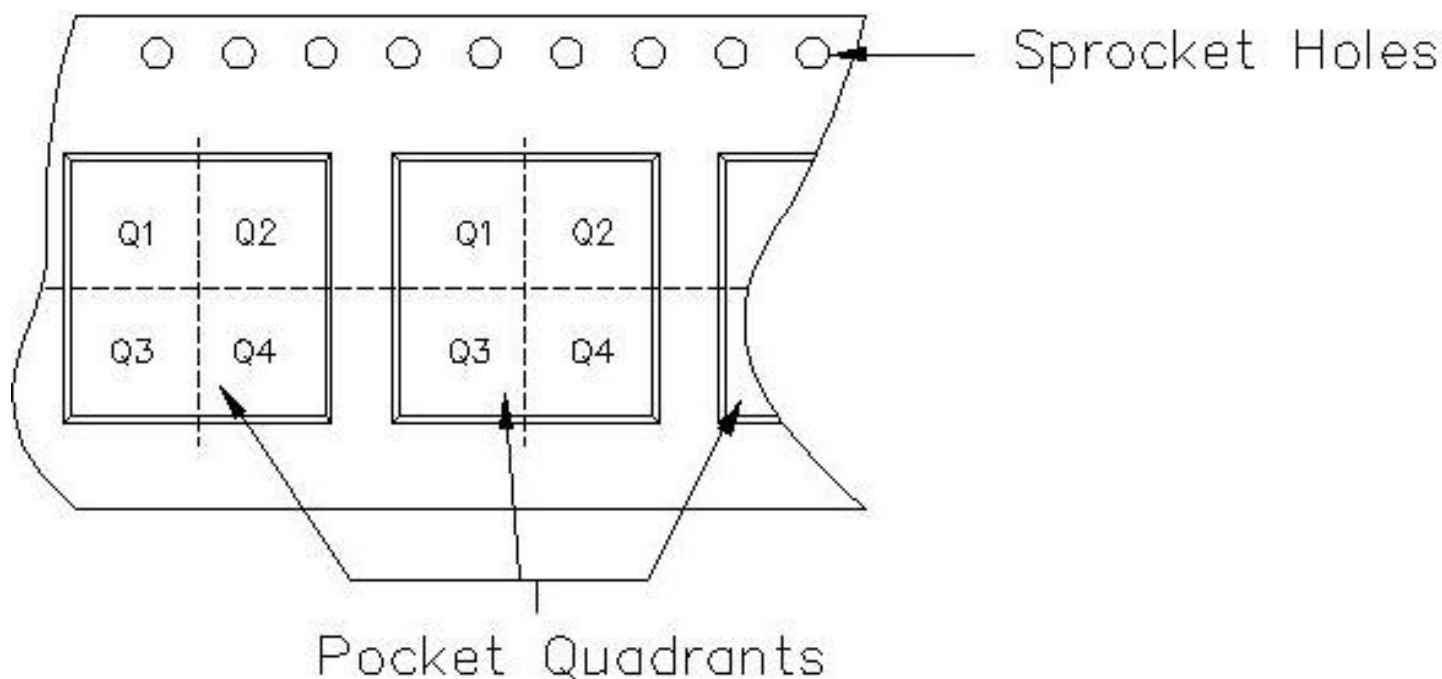
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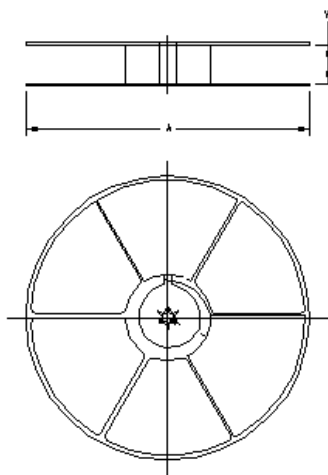
Carrier tape design is defined largely by the component length, width, and thickness.

|                                                                    |
|--------------------------------------------------------------------|
| $A_0$ = Dimension designed to accommodate the component width.     |
| $B_0$ = Dimension designed to accommodate the component length.    |
| $K_0$ = Dimension designed to accommodate the component thickness. |
| $W$ = Overall width of the carrier tape.                           |
| $P$ = Pitch between successive cavity centers.                     |



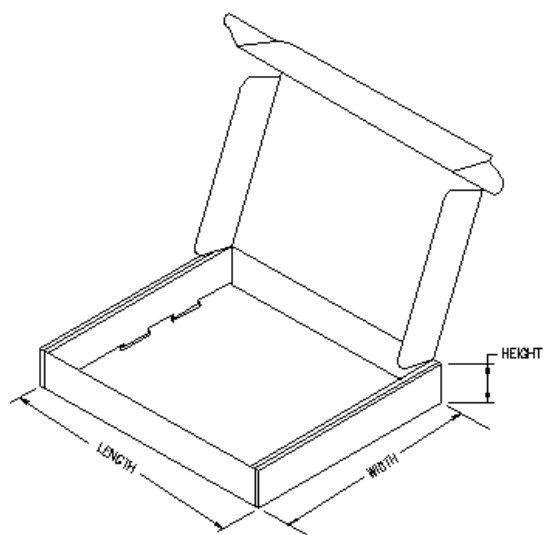
## TAPE AND REEL INFORMATION

| Device         | Package | Pins | Site    | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>(mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|----------------|---------|------|---------|--------------------------|-----------------------|---------|---------|---------|------------|-----------|------------------|
| TRF370315IRGER | RGE     | 24   | SITE 60 | 330                      | 12                    | 4.3     | 4.3     | 1.5     | 8          | 12        | Q1               |
| TRF370315IRGET | RGE     | 24   | SITE 60 | 330                      | 12                    | 4.3     | 4.3     | 1.5     | 8          | 12        | Q1               |
| TRF370333IRGER | RGE     | 24   | SITE 60 | 330                      | 12                    | 4.3     | 4.3     | 1.5     | 8          | 12        | Q2               |
| TRF370333IRGET | RGE     | 24   | SITE 60 | 330                      | 12                    | 4.3     | 4.3     | 1.5     | 8          | 12        | Q2               |



## TAPE AND REEL BOX INFORMATION

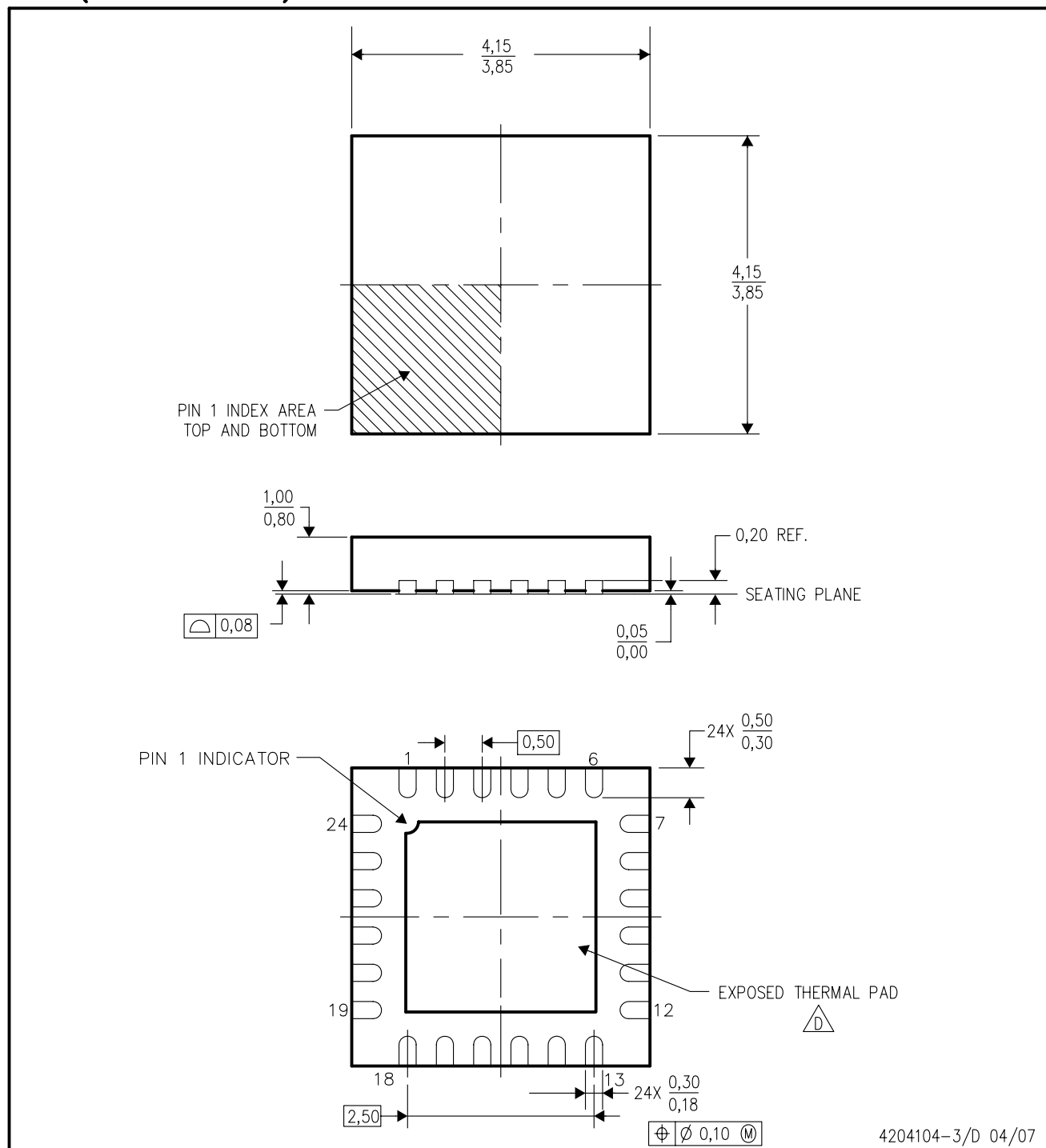
| Device         | Package | Pins | Site    | Length (mm) | Width (mm) | Height (mm) |
|----------------|---------|------|---------|-------------|------------|-------------|
| TRF370315IRGER | RGE     | 24   | SITE 60 | 342.9       | 336.6      | 20.64       |
| TRF370315IRGET | RGE     | 24   | SITE 60 | 407.0       | 336.6      | 97.0        |
| TRF370333IRGER | RGE     | 24   | SITE 60 | 342.9       | 336.6      | 20.64       |
| TRF370333IRGET | RGE     | 24   | SITE 60 | 342.9       | 336.6      | 20.64       |



## RGE (S-PQFP-N24)

## PIN 1 OPTION

## PLASTIC QUAD FLATPACK



NOTES:

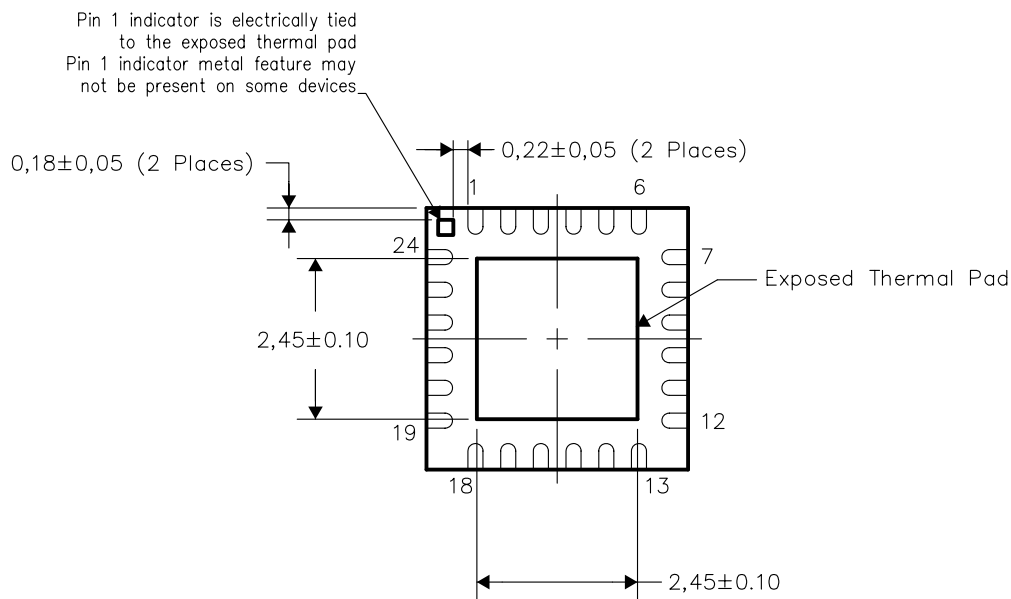
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-Leads (QFN) package configuration.
-  The package thermal pad must be soldered to the board for thermal and mechanical performance.  
See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
- E. Falls within JEDEC MO-220.

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to a ground or power plane (whichever is applicable), or alternatively, a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No-Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.

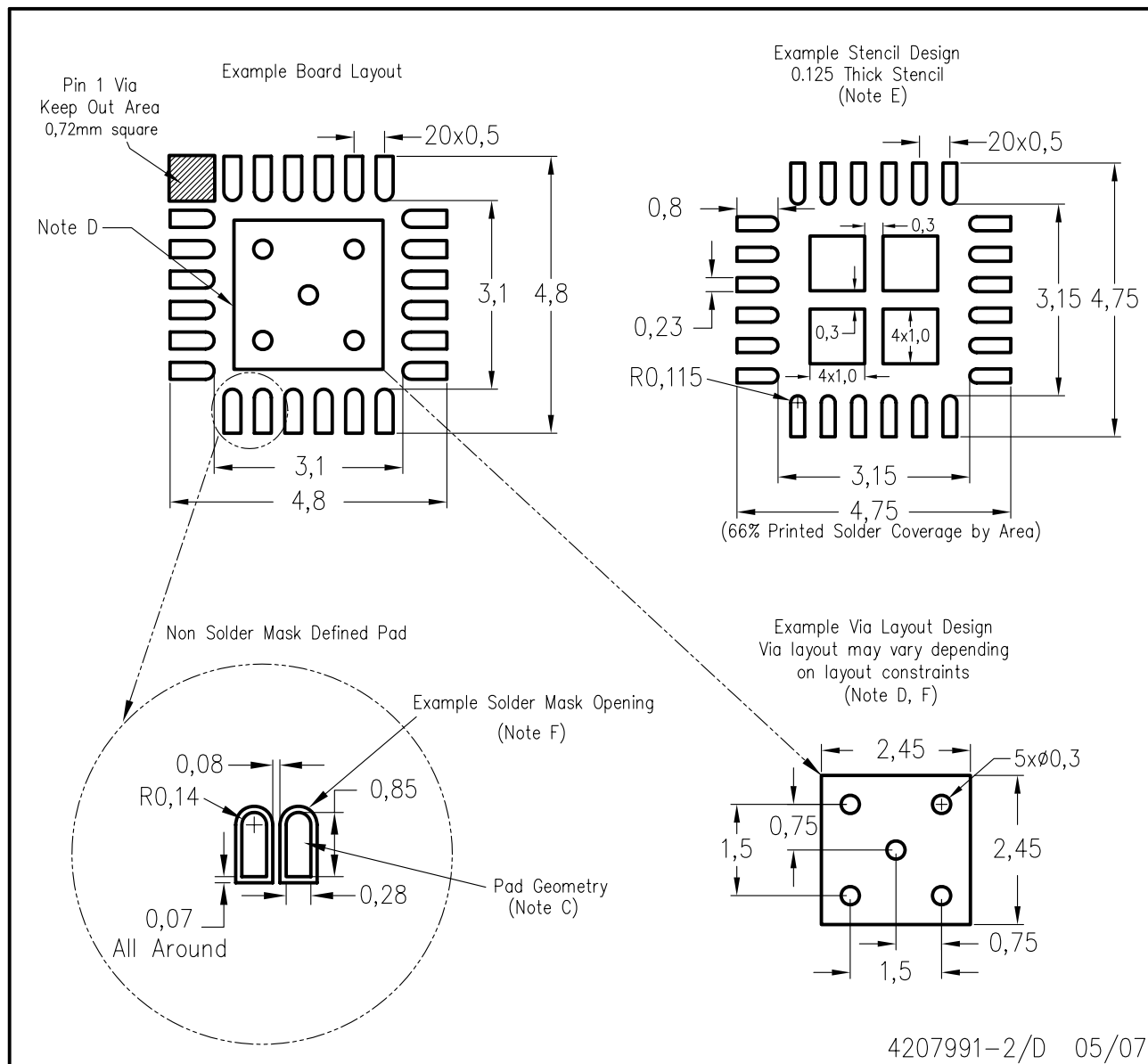


Bottom View

NOTE: All linear dimensions are in millimeters

## Exposed Thermal Pad Dimensions

# RGE (S-PQFP-N24)



4207991-2/D 05/07

- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

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| Data Converters  | <a href="http://dataconverter.ti.com">dataconverter.ti.com</a>     | Automotive         | <a href="http://www.ti.com/automotive">www.ti.com/automotive</a>         |
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| Logic            | <a href="http://logic.ti.com">logic.ti.com</a>                     | Military           | <a href="http://www.ti.com/military">www.ti.com/military</a>             |
| Power Mgmt       | <a href="http://power.ti.com">power.ti.com</a>                     | Optical Networking | <a href="http://www.ti.com/opticalnetwork">www.ti.com/opticalnetwork</a> |
| Microcontrollers | <a href="http://microcontroller.ti.com">microcontroller.ti.com</a> | Security           | <a href="http://www.ti.com/security">www.ti.com/security</a>             |
| RFID             | <a href="http://www.ti-rfid.com">www.ti-rfid.com</a>               | Telephony          | <a href="http://www.ti.com/telephony">www.ti.com/telephony</a>           |
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